

Now



**TPA3255** 

参考資料

JAJSD69A-FEBRUARY 2016-REVISED OCTOBER 2016

Support &

Community

22

## TPA3255 315Wステレオ、600Wモノラル、PurePath™ Ultra HDアナロ グ入力

Technical

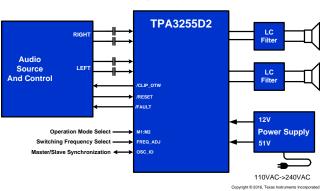
Documents

#### 特長 1

- 差動アナログ入力
- 10%THD+N時の総出力電力
  - BTL構成で4Ωへ315W (ステレオ)
  - BTL構成で8Ωへ185W (ステレオ)
  - PBTL構成で2Ω~600W (モノラル)
- 1%THD+N時の総出力電力
  - BTL構成で4Ωへ260W (ステレオ)
  - BTL構成で8Ω~150W (ステレオ)
  - PBTL構成で2Ω~480W (モノラル)
- 高度な統合フィードバック設計と、高速なゲー ト・ドライバ・エラー訂正

#### ( PurePath<sup>™</sup> Ultra-HD)

- 最高100kHzの信号帯域幅によりHDソースからの 高周波数のコンテンツに対応
- 非常に低いTHD+N: 4Ω~1Wで0.006%、クリッピ ングへ0.01%未満
- PSRR 65dB超(BTL、1kHz、入力信号なし)
- 出力ノイズ85µV未満(Aウェイト)
- SNR 111dB超(Aウェイト)
- 複数の構成が可能:
  - ステレオ、モノラル、2.1、4xSE
- 開始時と停止時にクリック音やポップ音が発生し ない
- 90%効率のClass-D動作(4Ω)
- 18V~53.5Vの広い電源電圧範囲での動作
- 自己保護設計(低電圧、過熱、クリッピング、短絡 保護を含む)とエラー報告機能
- 推奨システム設計で使用時にEMI準拠



### 概略回路図

#### 2 アプリケーション

🥭 Tools &

Software

- Blu-Rav Disc™/ DVDレシーバ
- ハイエンドHTiBシステム
- AVレシーバ .
- ハイエンド・サウンドバー
- ミニ・コンボ・システム
- アクティブ・スピーカーおよびサブウーファー

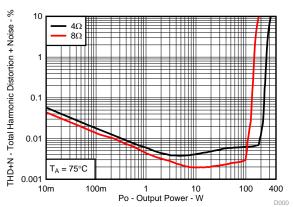
### 3 概要

TPA3255は高性能のClass-Dパワー・アンプで、最高の サウンド品質をClass-Dの効率で実現します。高度な統合 フィードバック設計と、独自の高速ゲート・ドライバ・エラー 訂正機能(PurePath™ Ultra-HD)があります。このテクノロ ジにより、音声帯域全体にわたる歪みが非常に低い、優 れたオーディオ品質を実現しています。このデバイスは ADモードで動作し、4Ω負荷へ10% THDで最大315× 2W、8Ω負荷へ最大2×150W (クリッピングなし)を駆動で き、2つのVRMSアナログ入力・インターフェイスが搭載さ れており、TIのPCM5242などの高性能DACとシームレス に動作します。非常に優れたオーディオ性能に加えて、 TPA3255は高い電力効率と、2.5Wという非常に低いパ ワー段のアイドル損失も実現しています。これらは、85mΩ MOSFETの使用と、最適化されたゲート・ドライバ方式に より、標準的なディスクリート実装よりもはるかに低いアイド ル損失を実現することで達成されています。

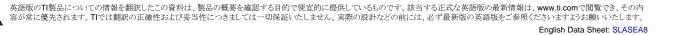
制品情報(1)

型番	パッケージ	本体サイズ(公称)		
TPA3255	HTSSOP (44)	6.10mm×14.00mm		

(1) 利用可能なすべてのパッケージについては、このデータシートの末 尾にある注文情報を参照してください。



#### 全高調波歪み





## 目次

1	特長1
2	アプリケーション1
3	既要1
4	收訂履歴2
5	Device Comparison Table 3
6	Pin Configuration and Functions
7	Specifications
	7.1 Absolute Maximum Ratings 5
	7.2 ESD Ratings 5
	7.3 Recommended Operating Conditions
	7.4 Thermal Information 6
	7.5 Electrical Characteristics
	7.6 Audio Characteristics (BTL) 8
	7.7 Audio Characteristics (SE) 9
	7.8 Audio Characteristics (PBTL)
	7.9 Typical Characteristics, BTL Configuration 10
	7.10 Typical Characteristics, SE Configuration 12
	7.11 Typical Characteristics, PBTL Configuration 13
8	Parameter Measurement Information 14
9	Detailed Description 14
	9.1 Overview 14

	9.2	Functional Block Diagrams	15
	9.3	Feature Description	17
	9.4	Device Functional Modes	
10	Арр	lication and Implementation	22
	10.1	Application Information	
	10.2	Typical Applications	22
11	Pow	er Supply Recommendations	29
	11.1	Power Supplies	
	11.2	Powering Up	30
	11.3	Powering Down	31
	11.4	Thermal Design	31
12	Layo	out	33
	12.1	Layout Guidelines	
	12.2	Layout Examples	34
13	デバ	イスおよびドキュメントのサポート	
	13.1	ドキュメントのサポート	37
	13.2	ドキュメントの更新通知を受け取る方法	37
	13.3	コミュニティ・リソース	37
	13.4	商標	37
	13.5	静電気放電に関する注意事項	37
	13.6	Glossary	37
14	メカニ	ニカル、パッケージ、および注文情報	37

## 4 改訂履歴

2016年2月発行のものから更新		
•	デバイスのステータスを製品プレビューから量産データへ変更	1

2



www.ti.com

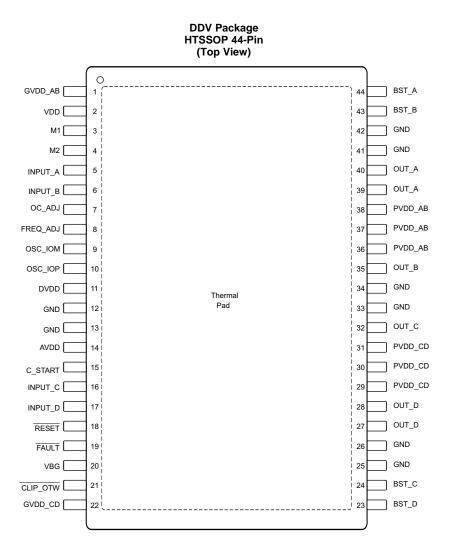
### 5 Device Comparison Table

DEVICE NAME	DESCRIPTION
TPA3244	40-W Stereo, 100-W peak PurePath™ Ultra-HD Pad Down Class-D Amplifier
TPA3245	100-W Stereo, 200-W Mono PurePath™ Ultra-HD Analog-Input Class-D Amplifier
TPA3250	70-W Stereo, 130-W peak PurePath™ Ultra-HD Pad Down Class-D Amplifier
TPA3251	175-W Stereo, 350-W Mono PurePath™ Ultra-HD Analog-Input Class-D Amplifier

### 6 Pin Configuration and Functions

The TPA3255 is available in a thermally enhanced TSSOP package.

The package type contains a PowerPAD<sup>™</sup> that is located on the top side of the device for convenient thermal coupling to the heat sink.



**TPA3255** JAJSD69A-FEBRUARY 2016-REVISED OCTOBER 2016

www.ti.com

**ISTRUMENTS** 

EXAS

	Pin Functions					
NAME	NO.	P	DESCRIPTION			
AVDD	14		Internal voltage regulator, analog section			
BST_A	44	P	HS bootstrap supply (BST), external 0.033 μF capacitor to OUT_A required.			
BST_B	43	Р	HS bootstrap supply (BST), external 0.033 µF capacitor to OUT_B required.			
BST_C	24	Р	HS bootstrap supply (BST), external 0.033 μF capacitor to OUT_C required.			
BST_D	23	Р	HS bootstrap supply (BST), external 0.033 μF capacitor to OUT_D required.			
CLIP_OTW	21	0	Clipping warning and Over-temperature warning; open drain; active low. Do not connect if not used.			
C_START	15	0	Startup ramp, requires a charging capacitor to GND			
DVDD	11	Р	Internal voltage regulator, digital section			
FAULT	19	0	Shutdown signal, open drain; active low. Do not connect if not used.			
FREQ_ADJ	8	0	Oscillator freqency programming pin			
GND	12, 13, 25, 26, 33, 34, 41, 42	Р	Ground			
GVDD_AB	1	Р	Gate-drive voltage supply; AB-side, requires 0.1 µF capacitor to GND			
GVDD_CD	22	Р	Gate-drive voltage supply; CD-side, requires 0.1 µF capacitor to GND			
NPUT_A	5	I	Input signal for half bridge A			
NPUT_B	6	I	Input signal for half bridge B			
NPUT_C	16	I	Input signal for half bridge C			
NPUT_D	17	I	Input signal for half bridge D			
M1	3	I	Mode selection 1 (LSB)			
M2	4	I	Mode selection 2 (MSB)			
C_ADJ	7	I/O	Over-Current threshold programming pin			
OSC_IOM	9	I/O	Oscillator synchronization interface. Do not connect if not used.			
OSC_IOP	10	0	Oscillator synchronization interface. Do not connect if not used.			
A_TUC	39, 40	0	Output, half bridge A			
OUT_B	35	0	Output, half bridge B			
OUT_C	32	0	Output, half bridge C			
OUT_D	27, 28	0	Output, half bridge D			
PVDD_AB	36, 37, 38	Р	PVDD supply for half-bridge A and B			
PVDD_CD	29, 30, 31	Р	PVDD supply for half-bridge C and D			
RESET	18	I	Device reset Input; active low			
VDD	2	Р	Power supply for internal voltage regulator requires a 10-µF capacitor with a 0.1-µF capacitor to GND for decoupling.			
VBG	20	Р	Internal voltage reference requires a 1-µF capacitor to GND for decoupling.			
PowerPad™		Р	Ground, connect to grounded heat sink			

...

----\_

#### **Table 1. Mode Selection Pins**

	DDE NS <sup>(1)</sup>	INPUT MODE <sup>(2)</sup>	OUTPUT CONFIGURATION	DESCRIPTION					
M2	M1		CONFIGURATION						
0	0	2N + 1	2 × BTL	Stereo BTL output configuration					
0	1	2N/1N + 1	1 x BTL + 2 x SE	1 x BTL + 2 x SE 2.1 BTL + SE mode. Channel AB: BTL, channel C + D: SE					
					INPUT_C	INPUT_D			
1	0	2N + 1	1 x PBTL	Parallelled BTL configuration. Connect INPUT_C and INPUT_D to GND. <sup>(1)</sup>	0	0			
	Ū	211 + 1	1 x BTL	Mono BTL configuration. BTL channel AB active, channel CD not switching. Connect INPUT_C to DVDD and INPUT_D to GND. <sup>(1)</sup>	1	0			
1	1	1N +1	4 x SE	Single ended output configuration					

1 refers to logic high (DVDD level), 0 refers to logic low (GND). 2N refers to differential input signal, 1N refers to single ended input signal. +1 refers to number of logic control (RESET) input pins. (1) (2)



## 7 Specifications

#### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
	BST_X to GVDD_X <sup>(2)</sup>	-0.3	69	V
	VDD to GND	-0.3	13.2	V
	GVDD_X to GND <sup>(2)</sup>	-0.3	13.2	V
Supply voltage	PVDD_X to GND <sup>(2)</sup>	-0.3	69	V
	DVDD to GND	-0.3	4.2	V
	AVDD to GND	-0.3	8.5	V
	VBG to GND	-0.3	4.2	V
	OUT_X to GND <sup>(2)</sup>	-0.3	69	V
	BST_X to GND <sup>(2)</sup>	-0.3	81.5	V
Interfere size	OC_ADJ, M1, M2, OSC_IOP, OSC_IOM, FREQ_ADJ, C_START, to GND	-0.3	4.2	V
interrace pins	RESET, FAULT, CLIP_OTW to GND	-0.3	4.2	V
Interface pins	INPUT_X to GND	-0.3	7	V
	Continuous sink current, RESET, FAULT, CLIP_OTW to GND		9	mA
TJ	Operating junction temperature range	0	150	°C
T <sub>stg</sub>	Storage temperature range	-40	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) These voltages represents the DC voltage + peak AC waveform measured at the terminal of the device in all conditions.

#### 7.2 ESD Ratings

			VALUE	UNIT
N/		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins $^{\left(1\right)}$	±2000	V
V <sub>ESD</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

JAJSD69A-FEBRUARY 2016-REVISED OCTOBER 2016

www.ti.com

STRUMENTS

EXAS

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT	
PVDD x	Half-bridge supply	DC supply voltage, $R_L = 4\Omega$	18	51	53.5	V	
PVDD_X	Hall-blidge supply	DC supply voltage, $R_L \ge 6\Omega^{(1)}$	18	53.5	56.5		
GVDD_x	Supply for logic regulators and gate-drive circuitry	DC supply voltage	10.8	12	13.2	V	
VDD	Digital regulator supply voltage	DC supply voltage	10.8	12	13.2	V	
R <sub>L</sub> (BTL)			3.4	4			
R <sub>L</sub> (SE)	Load impedance	Output filter inductance within recommended value range	1.7	3		Ω	
R <sub>L</sub> (PBTL)			1.7	2			
L <sub>OUT</sub> (BTL)			5				
L <sub>OUT</sub> (SE)	Output filter inductance	Minimum output inductance at I <sub>OC</sub>	5			μH	
L <sub>OUT</sub> (PBTL)			5				
F <sub>PWM</sub>	PWM frame rate selectable for AM interference avoidance; 1% Resistor tolerance	Nominal	430	450	470		
		AM1	475	500	525	kHz	
		AM2	575	600	625		
	PWM frame rate programming resistor	Nominal; Master mode	29.7	30	30.3	kΩ	
R <sub>(FREQ_ADJ)</sub>		AM1; Master mode	19.8	20	20.2		
		AM2; Master mode	9.9	10	10.1		
C <sub>PVDD</sub>	PVDD close decoupling capacitors			1		μF	
		Resistor tolerance = 5%, $R_L = 4\Omega$	22		30		
R <sub>OC</sub>	Over-current programming resistor	Resistor tolerance = 5%, $R_L \ge 6\Omega$ , PVDD = 53.5V <sup>(1)</sup>		30		kΩ	
		Resistor tolerance = 5%, $R_L = 4\Omega$	47		64		
R <sub>OC(LATCHED)</sub>	Over-current programming resistor	Resistor tolerance = 5%, $R_L \ge 6\Omega$ , PVDD = 53.5V <sup>(1)</sup>		64		kΩ	
V <sub>(FREQ_ADJ)</sub>	Voltage on FREQ_ADJ pin for slave mode operation	Slave mode		3.3		V	
TJ	Junction temperature		0		125	°C	

(1) For load impedance  $\geq 6\Omega$  PVDD can be increased, provided a reduced over-current threshold is set

### 7.4 Thermal Information

		TPA	TPA3255			
		DDV 44-PIN	DDV 44-PINS HTSSOP			
THERMAL METRIC <sup>(1)</sup> R <sub>0JA</sub> Junction-to-ambient thermal resistance         R <sub>0JC(top)</sub> Junction-to-case (top) thermal resistance         R <sub>0JB</sub> Junction-to-board thermal resistance         Ψ <sub>JT</sub> Junction-to-top characterization parameter         Ψ <sub>JB</sub> Junction-to-board characterization parameter         P       Junction-to-board characterization parameter	JEDEC STANDARD 4 LAYER PCB	FIXED 85°C HEATSINK TEMPERATURE <sup>(2)</sup>	UNIT			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	50.7	2.4 <sup>(2)</sup>			
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	DDV 44-PINS HTSSOPJEDEC STANDARD 4 LAYER PCBFIXED 85°C HEATSINK TEMPERATURE(2)esistance50.72.4(2)resistance0.360.3stance24.4n/an parameter0.190.5ttion parameter24.2n/a				
$R_{\theta JB}$	Junction-to-board thermal resistance	24.4	n/a	°C/W		
ΨJT	Junction-to-top characterization parameter	0.19	0.5	C/VV		
Ψјв	Junction-to-board characterization parameter	24.2	n/a			
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a			

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

(2) Thermal data are obtained with 85°C heat sink temperature using thermal compound with 0.7W/mK thermal conductivity and 2mil thickness. In this model heat sink temperature is considered to be the ambient temperature and only path for dissipation is to the heatsink.



## 7.5 Electrical Characteristics

 $\underline{PVDD}_X = 51 \text{ V}, \text{ } \text{GVDD}_X = 12 \text{ V}, \text{ } \text{VDD} = 12 \text{ V}, \text{ } \text{T}_{\text{C}} \text{ (Case temperature)} = 75^{\circ}\text{C}, \text{ } \text{f}_{\text{S}} = 450 \text{ kHz}, \text{ } \text{unless otherwise specified}.$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INTERNAL VOLTAG	E REGULATOR AND CURRENT CONSUMP	TION				
DVDD	Voltage regulator, only used as reference node	VDD = 12 V	3	3.3	3.6	V
AVDD	Voltage regulator, only used as reference node	VDD = 12 V		7.75		V
		Operating, 50% duty cycle		30		
I <sub>VDD</sub>	VDD supply current	Idle, reset mode		14		mA
		50% duty cycle		44		
I <sub>GVDD_X</sub>	Gate-supply current per full-bridge	Reset mode		5		mA
		50% duty cycle with recommended output filter		24		mA
I <sub>PVDD_X</sub>	PVDD idle current per full bridge	Reset mode, No switching		5		mA
_		$VDD = 0V, GVDD_X = 0V$		1.25		mA
ANALOG INPUTS	1	1	1			
R <sub>IN</sub>	Input resistance			20		kΩ
V <sub>IN</sub>	Maximum input voltage swing, peak - peak				7	V
I <sub>IN</sub>	Maximum input current				1	mA
G	Inverting voltage Gain	V <sub>OUT</sub> /V <sub>IN</sub>		21.5		dB
OSCILLATOR						
	Nominal, Master Mode		2.58	2.7	2.82	
faceura	AM1, Master Mode	 F <sub>PWM</sub> × 6	2.30	3	3.15	MHz
f <sub>OSC(IO+)</sub>	AM2. Master Mode		3.45	3.6	3.75	111112
V <sub>IH</sub>	High level input voltage		3.45 1.86	0.0	5.15	V
VIII VIII	Low level input voltage		1.00		1.45	V
VIL OUTPUT-STAGE MO	, <u>,</u>				1.40	v
OUIFUI-STAGE MO		<b>T 0700 1 1 1 1 1 1</b>		0 <i>F</i>	100	
R <sub>DS(on)</sub>	Drain-to-source resistance, low side (LS)	$T_J = 25^{\circ}$ C, Includes metallization resistance, GVDD = 12 V		85	100	mΩ
I/O PROTECTION	Drain-to-source resistance, high side (HS)	0000 - 12 0		85	100	mΩ
V <sub>uvp,VDD,GVDD</sub>	Undervoltage protection limit, GVDD_x and VDD			8.7		V
V <sub>uvp,VDD, GVDD,hyst</sub> (1)				0.6		V
V <sub>uvp,PVDD</sub>	Undervoltage protection limit, PVDD_x			14.5		v
Vuvp,PVDD Vuvp,PVDD,hyst <sup>(1)</sup>				1.4		V
OTW	Overtemperature warning, CLIP_OTW <sup>(1)</sup>		110	120	130	°C
OTW <sub>hyst</sub> <sup>(1)</sup>	Temperature drop needed below OTW temperature for CLIP_OTW to be inactive after OTW event.			20	100	°C
OTE <sup>(1)</sup>	Overtemperature error		140	150	160	°C
OTE <sub>hyst</sub> <sup>(1)</sup>	A reset needs to occur for FAULT to be released following an OTE event			15		°C
OTE-OTW <sub>(differential)</sub>	OTE-OTW differential			30		°C
OLPC	Overload protection counter	f <sub>PWM</sub> = 450 kHz (1024 PWM cycles)		2.3		ms
l	Overcurrent limit protection	Resistor – programmable, nominal peak current in 1 $\Omega$ load, $R_{OCP}$ = 22 $k\Omega$		17		А
l <sub>oc</sub>		Resistor – programmable, nominal peak current in 1 $\Omega$ load, $R_{OCP}$ = 30 $k\Omega$		13		A
	Overcurrent limit protection	Resistor – programmable, peak current in $1\Omega$ load, $R_{OCP}$ = $47k\Omega$		17		А
		Resistor – programmable, peak current in 1 $\Omega$ load, $R_{OCP}$ = 64k $\Omega$		13		
I <sub>DCspkr</sub>	DC Speaker Protection Current Threshold	BTL current imbalance threshold		1.5		А
I <sub>OCT</sub>	Overcurrent response time	Time from switching transition to flip-state induced by overcurrent.		150		ns

(1) Specified by design.

### **Electrical Characteristics (continued)**

PVDD\_X = 51 V, GVDD\_X = 12 V, VDD = 12 V, T<sub>C</sub> (Case temperature) = 75°C, f<sub>S</sub> = 450 kHz, unless otherwise specified.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>PD</sub>	Output pulldown current of each half	Connected when RESET is active to provide bootstrap charge. Not used in SE mode.		3		mA
STATIC DIGITAL	SPECIFICATIONS					
V <sub>IH</sub>	High level input voltage	M1, M2, OSC IOP, OSC IOM, RESET	1.9			V
VIL	Low level input voltage	MI, MZ, OSC_IOP, OSC_IOM, RESET			0.8	V
l <sub>lkg</sub>	Input leakage current				100	μA
OTW/SHUTDOW	N (FAULT)					
R <sub>INT_PU</sub>	Internal <u>pullup</u> resistance, CLIP_OTW to DVDD, FAULT to DVDD		20	26	32	kΩ
V <sub>OH</sub>	High level output voltage	Internal pullup resistor	3	3.3	3.6	V
V <sub>OL</sub>	Low level output voltage	I <sub>O</sub> = 4 mA		10	500	mV
Device fanout	CLIP_OTW, FAULT	No external pullup		30		devices

### 7.6 Audio Characteristics (BTL)

PCB and system configuration are in accordance with recommended guidelines. Audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 4  $\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 10  $\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, mode = 00, AES17 + AUX-0025 measurement filters, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
		$R_L = 4 \Omega$ , 10% THD+N	315		
P <sub>O</sub> Power		$R_L = 6 \Omega$ , 10% THD+N, PVDD = 53.5V	250		
	Dewer output per channel	$R_L = 8 \Omega$ , 10% THD+N, PVDD = 53.5V	195		W
	Power output per channel	$R_L = 4 \Omega$ , 1% THD+N	255		vv
		$R_L$ = 6 $\Omega$ , 1% THD+N, PVDD = 53.5V	200		
		$R_L$ = 8 $\Omega$ , 1% THD+N, PVDD = 53.5V	155		
THD+N	Total harmonic distortion + noise	1 W	0.006%		
Vn	Output integrated noise	A-weighted, AES17 filter, Input Capacitor Grounded	85		μV
V <sub>OS</sub>	Output offset voltage	Inputs AC coupled to GND	15	60	mV
SNR	Signal-to-noise ratio <sup>(1)</sup>		112		dB
DNR	Dynamic range		113		dB
P <sub>idle</sub>	Power dissipation due to Idle losses (I <sub>PVDD</sub> )	$P_0 = 0, 4$ channels switching <sup>(2)</sup>	2.5		W

(1) SNR is calculated relative to 1% THD+N output level.

(2) Actual system idle losses also are affected by core losses of output inductors.



#### 7.7 Audio Characteristics (SE)

PCB and system configuration are in accordance with recommended guidelines. Audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 2  $\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 15  $\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, MODE = 11, AES17 + AUX-0025 measurement filters, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN TYP M	AX UNIT
		R <sub>L</sub> = 2 Ω, 10% THD+N	148	
Po		$R_L$ = 3 $\Omega$ , 10% THD+N, PVDD = 53.5V	120	
	Dower output per channel	$R_L$ = 4 $\Omega$ , 10% THD+N, PVDD = 53.5V	95	w
	Power output per channel	$R_L = 2 \Omega$ , 1% THD+N	120	vv
		$R_L$ = 3 $\Omega$ , 1% THD+N, PVDD = 53.5V	98	
		$R_L = 4 \Omega$ , 1% THD+N, PVDD = 53.5V	77	
THD+N	Total harmonic distortion + noise	1 W	0.04%	
V <sub>n</sub>	Output integrated noise	A-weighted, AES17 filter, Input Capacitor Grounded	160	μV
SNR	Signal to noise ratio <sup>(1)</sup>	A-weighted	101	dB
DNR	Dynamic range	A-weighted	101	dB
P <sub>idle</sub>	Power dissipation due to idle losses (IPVDD)	$P_O = 0, 4$ channels switching <sup>(2)</sup>	2	W

(1) SNR is calculated relative to 1% THD+N output level.

(2) Actual system idle losses are affected by core losses of output inductors.

#### 7.8 Audio Characteristics (PBTL)

PCB and system configuration are in accordance with recommended guidelines. Audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 2  $\Omega$ , f<sub>s</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 10  $\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, MODE = 10, AES17 + AUX-0025 measurement filters, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
		$R_L = 2 \Omega$ , 10% THD+N	605	
		$R_L$ = 3 $\Omega$ , 10% THD+N, PVDD = 53.5V	500	
D	Dower output per channel	$R_L = 4 \Omega$ , 10% THD+N, PVDD = 53.5V	390	w
Po	Power output per channel	$R_L = 2 \Omega$ , 1% THD+N	495	vv
		$R_L = 3 \Omega$ , 1% THD+N, PVDD = 53.5V	405	
		$R_L = 4 \Omega$ , 1% THD+N, PVDD = 53.5V	315	
THD+N	Total harmonic distortion + noise	1 W	0.008%	
Vn	Output integrated noise	A-weighted, AES17 filter, Input Capacitor Grounded	70	μV
SNR	Signal to noise ratio <sup>(1)</sup>	A-weighted	114	dB
DNR	Dynamic range	A-weighted	114	dB
P <sub>idle</sub>	Power dissipation due to idle losses (IPVDD)	$P_0 = 0, 4$ channels switching <sup>(2)</sup>	2.5	W

(1) SNR is calculated relative to 1% THD+N output level.

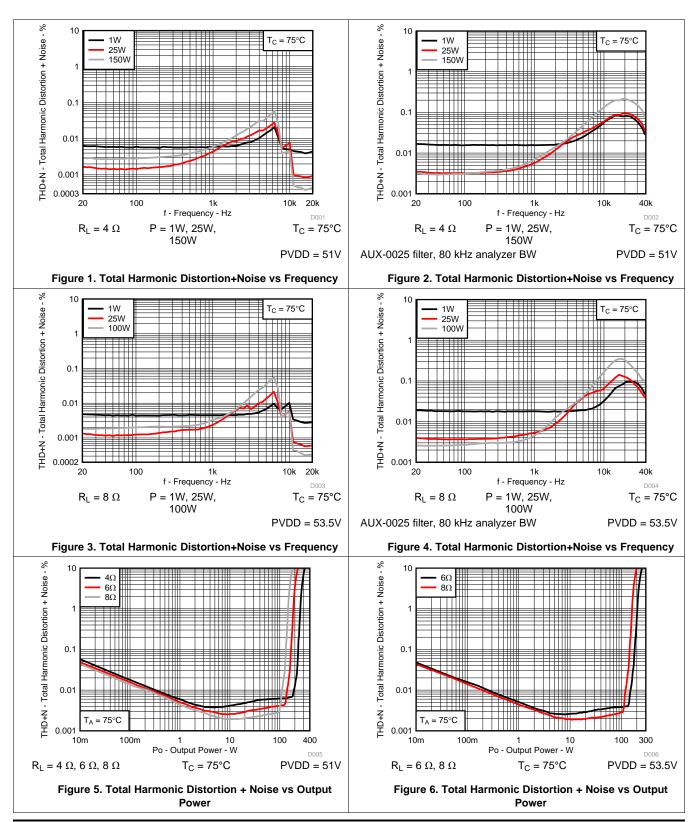
(2) Actual system idle losses are affected by core losses of output inductors.



**TPA3255** JAJSD69A – FEBRUARY 2016 – REVISED OCTOBER 2016

### 7.9 Typical Characteristics, BTL Configuration

All Measurements taken at audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 4  $\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 10  $\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, mode = 00, AES17 + AUX-0025 measurement filters, unless otherwise noted.

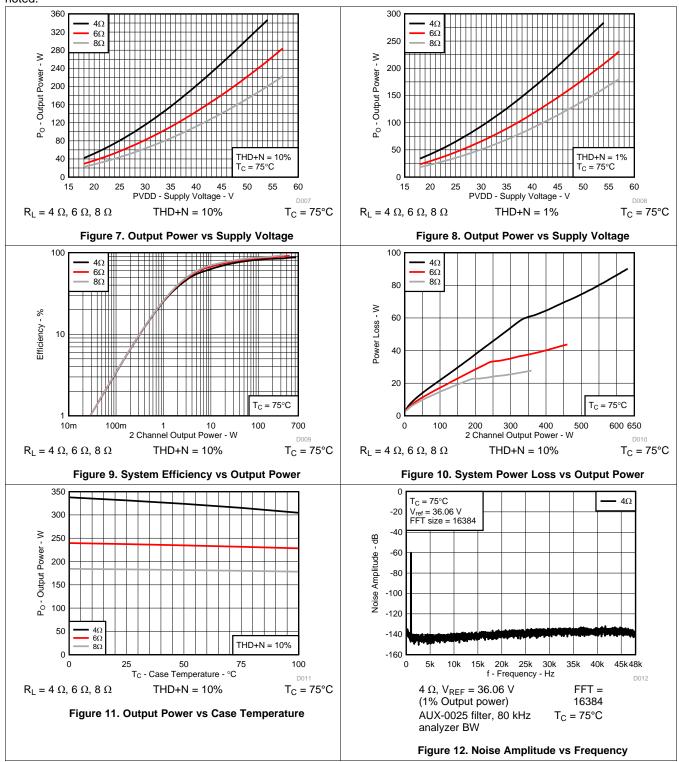


Copyright © 2016, Texas Instruments Incorporated



#### **Typical Characteristics, BTL Configuration (continued)**

All Measurements taken at audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 4  $\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 10  $\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, mode = 00, AES17 + AUX-0025 measurement filters, unless otherwise noted.

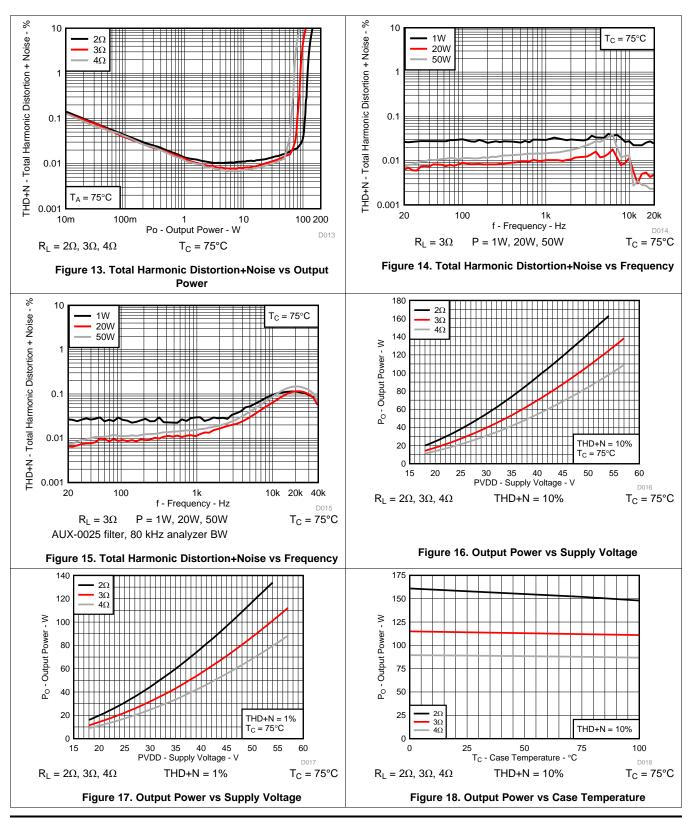




TPA3255 JAJSD69A – FEBRUARY 2016 – REVISED OCTOBER 2016

### 7.10 Typical Characteristics, SE Configuration

All Measurements taken at audio frequency = 1 kHz, PVDD\_X = 51 V, GVDD\_X = 12 V, R<sub>L</sub> = 3  $\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> = 22 k $\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> = 15  $\mu$ H, C<sub>DEM</sub> = 680 nF, MODE = 11, AES17 + AUX-0025 measurement filters, unless otherwise noted.

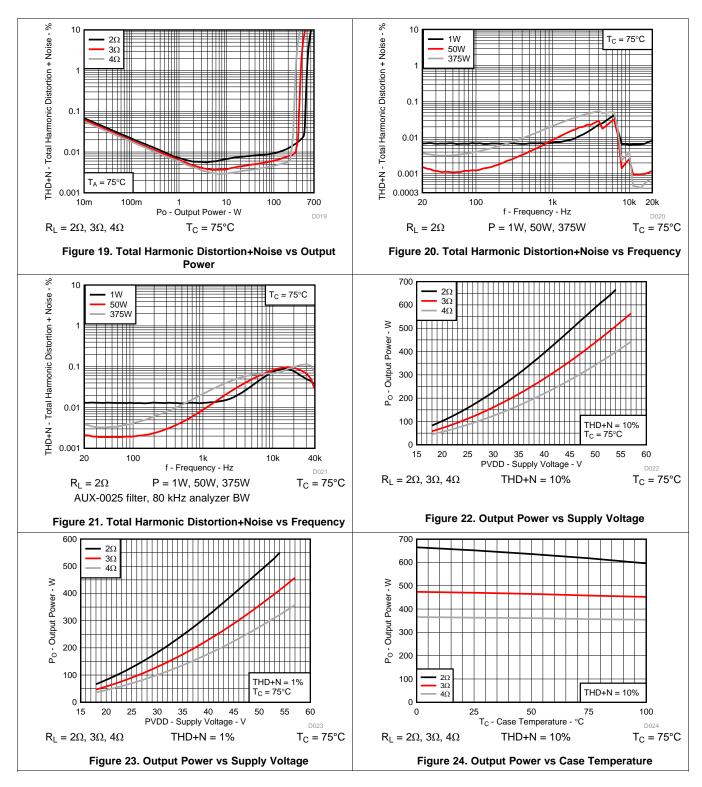


Copyright © 2016, Texas Instruments Incorporated



#### 7.11 Typical Characteristics, PBTL Configuration

All Measurements taken at audio frequency = 1 kHz, PVDD\_X = 51V, GVDD\_X = 12 V, R<sub>L</sub> =  $2\Omega$ , f<sub>S</sub> = 450 kHz, R<sub>OC</sub> =  $22 k\Omega$ , T<sub>C</sub> = 75°C, Output Filter: L<sub>DEM</sub> =  $10\mu$ H, C<sub>DEM</sub> = 1  $\mu$ F, MODE = 10, AES17 + AUX-0025 measurement filters, unless otherwise noted.





### 8 Parameter Measurement Information

All parameters are measured according to the conditions described in the *Recommended Operating Conditions*, *Typical Characteristics*, *BTL Configuration*, *Typical Characteristics*, *SE Configuration* and *Typical Characteristics*, *PBTL Configuration* sections.

Most audio analyzers will not give correct readings of Class-D amplifiers' performance due to their sensitivity to out of band noise present at the amplifier output. AES-17 + AUX-0025 pre-analyzer filters are recommended to use for Class-D amplifier measurements. In absence of such filters, a 30-kHz low-pass filter (10  $\Omega$  + 47 nF) can be used to reduce the out of band noise remaining on the amplifier outputs.

### 9 Detailed Description

#### 9.1 Overview

To facilitate system design, the TPA3255 needs only a 12-V supply in addition to the (typical) 51-V power-stage supply. An internal voltage regulator provides suitable voltage levels for the digital and low-voltage analog circuitry, AVDD and DVDD. Additionally, all circuitry requiring a floating voltage supply, that is, the high-side gate drive, is accommodated by built-in bootstrap circuitry requiring only an external capacitor for each half-bridge.

The audio signal path including gate drive and output stage is designed as identical, independent half-bridges. For this reason, each half-bridge has separate bootstrap pins (BST\_X). Power-stage supply pins (PVDD\_X) and gate drive supply pins (GVDD\_X) are separate for each full bridge. Although supplied from the same 12-V source, separating to GVDD\_AB, GVDD\_CD, and VDD on the printed-circuit board (PCB) by RC filters (see application diagram for details) is recommended. These RC filters provide the recommended high-frequency isolation. Special attention should be paid to placing all decoupling capacitors as close to their associated pins as possible. In general, the physical loop with the power supply pins, decoupling capacitors and GND return path to the device pins must be kept as short as possible and with as little area as possible to minimize induction (see reference board documentation for additional information).

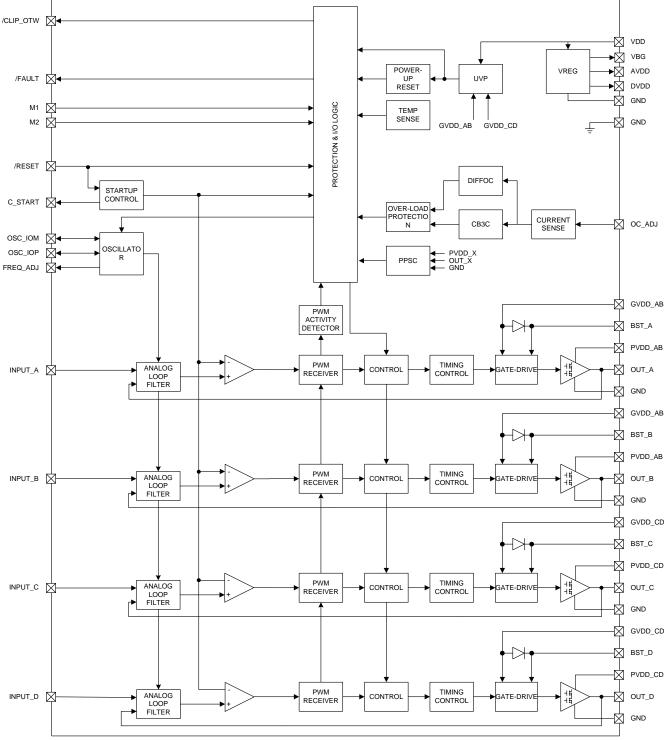
For a properly functioning bootstrap circuit, a small ceramic capacitor must be connected from each bootstrap pin (BST\_X) to the power-stage output pin (OUT\_X). When the power-stage output is low, the bootstrap capacitor is charged through an internal diode connected between the gate-drive power-supply pin (GVDD\_X) and the bootstrap pins. When the power-stage output is high, the bootstrap capacitor potential is shifted above the output potential and thus provides a suitable voltage supply for the high-side gate driver. It is recommended to use 33-nF ceramic capacitors, size 0603 or 0805, for the bootstrap supply. These 33nF capacitors ensure sufficient energy storage, even during minimal PWM duty cycles, to keep the high-side power stage FET (LDMOS) fully turned on during the remaining part of the PWM cycle.

Special attention should be paid to the power-stage power supply; this includes component selection, PCB placement, and routing. As indicated, each full-bridge has independent power-stage supply pins (PVDD\_X). For optimal electrical performance, EMI compliance, and system reliability, it is important that each PVDD\_X node is decoupled with  $1-\mu$ F ceramic capacitor placed as close as possible to the supply pins. It is recommended to follow the PCB layout of the TPA3255 reference design. For additional information on recommended power supply and required components, see the application diagrams in this data sheet.

The 12-V supply should be from a low-noise, low-output-impedance voltage regulator. Likewise, the 51-V powerstage supply is assumed to have low output impedance and low noise. The power-supply sequence is not critical as facilitated by the internal power-on-reset circuit, but it is recommended to release RESET after the power supply is settled for minimum turn on audible artefacts. Moreover, the TPA3255 is fully protected against erroneous power-stage turn on due to parasitic gate charging. Thus, voltage-supply ramp rates (dV/dt) are noncritical within the specified range (see the *Recommended Operating Conditions* table of this data sheet).



#### 9.2 Functional Block Diagrams

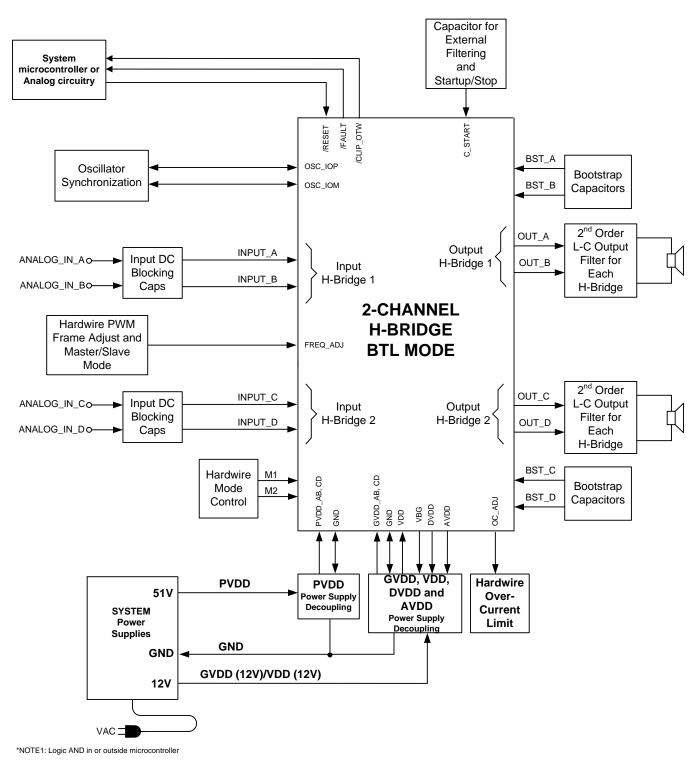


Copyright © 2016, Texas Instruments Incorporated

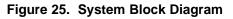
TEXAS INSTRUMENTS

www.ti.com

### **Functional Block Diagrams (continued)**



Copyright © 2016, Texas Instruments Incorporated





#### 9.3 Feature Description

#### 9.3.1 Error Reporting

The FAULT, and CLIP\_OTW, pins are active-low, open-drain outputs. The function is for protection-mode signaling to a system-control device.

Any fault resulting in device shutdown is signaled by the FAULT pin going low. Also, CLIP\_OTW goes low when the device junction temperature exceeds 125°C (see Table 2).

FAULT	CLIP_OTW	DESCRIPTION
0	0	Overtemperature (OTE) or overload (OLP) or undervoltage (UVP) Junction temperature higher than 125°C (overtemperature warning)
0	0	Overload (OLP) or undervoltage (UVP). Junction temperature higher than 125°C (overtemperature warning)
0	1	Overload (OLP) or undervoltage (UVP). Junction temperature lower than 125°C
1	0	Junction temperature higher than 125°C (overtemperature warning)
1	1	Junction temperature lower than 125°C and no OLP or UVP faults (normal operation)

 Table 2. Error Reporting

Note that asserting RESET low forces the FAULT signal high, independent of faults being present. TI recommends monitoring the CLIP\_OTW signal using the system microcontroller and responding to an overtemperature warning signal by turning down the volume to prevent further heating of the device resulting in device shutdown (OTE).

To reduce external component count, an internal pullup resistor to 3.3 V is provided on both FAULT and CLIP\_OTW outputs.

#### 9.4 Device Functional Modes

#### 9.4.1 Device Protection System

The TPA3255 contains advanced protection circuitry carefully designed to facilitate system integration and ease of use, as well as to safeguard the device from permanent failure due to a wide range of fault conditions such as short circuits, overload, overtemperature, and undervoltage. The TPA3255 responds to a fault by immediately setting the power stage in a high-impedance (Hi-Z) state and asserting the FAULT pin low. In situations other than overload and overtemperature error (OTE), the device automatically recovers when the fault condition has been removed, that is, the supply voltage has increased.

The device will handle errors, as shown in Table 3.

BTL MODE		PBTL MODE		SE MODE	
LOCAL ERROR IN	TURNS OFF	LOCAL ERROR IN	TURNS OFF	LOCAL ERROR IN	TURNS OFF
А	A+B	А		А	A+B
В	A+D	В		В	A+D
С		С	A+B+C+D	С	
D	C+D	D		D	C+D

Table 3.	Device	Protection
----------	--------	------------

Bootstrap UVP does not shutdown according to the table, it shuts down the respective halfbridge (non-latching, does not assert FAULT).

#### 9.4.1.1 Overload and Short Circuit Current Protection

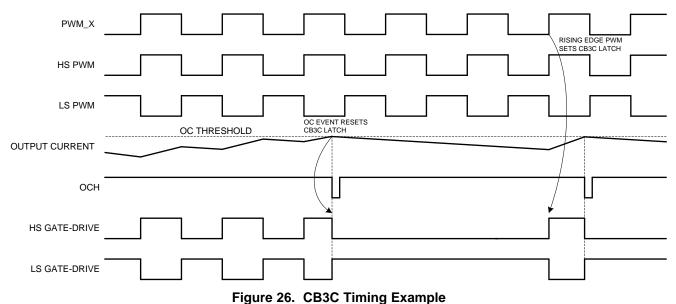
TPA3255 has fast reacting current sensors with a programmable trip threshold (OC threshold) on all high-side and low-side FETs. To prevent output current from increasing beyond the programmed threshold, TPA3255 has the option of either limiting the output current for each switching cycle (Cycle By Cycle Current Control, CB3C) or to perform an immediate shutdown of the output in case of excess output current (Latching Shutdown). CB3C prevents premature shutdown due to high output current transients caused by high level music transients and a TPA3255 JAJSD69A – FEBRUARY 2016 – REVISED OCTOBER 2016

www.ti.com

**NSTRUMENTS** 

ÈXAS

drop of real speaker's load impedance, and allows the output current to be limited to a maximum programmed level. If the maximum output current persists, i.e. the power stage being overloaded with too low load impedance, the device will shut down the affected output channel and the affected output is put in a high-impedance (Hi- Z) state until a RESET cycle is initiated. CB3C works individually for each half bridge output. If an over current event is triggered, CB3C performs a state flip of the half bridge output that is cleared upon beginning of next PWM frame.



During CB3C an over load counter increments for each over current event and decrease for each non-over current PWM cycle. This allows full amplitude transients into a low speaker impedance without a shutdown protection action. In the event of a short circuit condition, the over current protection limits the output current by the CB3C operation and eventually shut down the affected output if the overload counter reaches its maximum value. If a latched OC operation is required such that the device shuts down the affected output immediately upon first detected over current event, this protection mode should be selected. The over current threshold and mode (CB3C or Latched OC) is programmed by the OC\_ADJ resistor value. The OC\_ADJ resistor needs to be within its intentional value range for either CB3C operation or Latched OC operation.

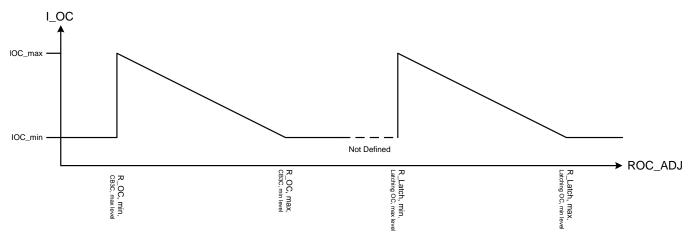


Figure 27. OC Threshold versus OC\_ADJ Resistor Value Example

OC\_ADJ values outside specified value range for either CB3C or latched OC operation will result in minimum OC threshold.



OC_ADJ Resistor Value	Protection Mode	OC Threshold
<b>22k</b> Ω	CB3C	17.0A
24kΩ	CB3C	15.7A
27kΩ	CB3C	14.2A
30kΩ	CB3C	12.9A
47kΩ	Latched OC	17.0A
51kΩ	Latched OC	15.7A
56kΩ	Latched OC	14.2A
64kΩ	Latched OC	12.9A

#### **Table 4. Device Protection**

#### 9.4.1.2 Signal Clipping and Pulse Injector

A built in activity detector monitors the PWM activity of the OUT\_X pins. TPA3255 is designed to drive unclipped output signals all the way to PVDD and GND rails. In case of audio signal clipping when applying excessive input signal voltage, or in case of CB3C current protection being active, the amplifier feedback loop of the audio channel will respond to this condition with a saturated state, and the output PWM signals would stop if the device did not have special circuitry implemented to handle this situation. To prevent the output PWM signals from stopping in a clipping or CB3C situation, narrow pulses are injected to the gate drive to maintain output activity. The injected narrow pulses are injected at every 4<sup>th</sup> PWM frame, and thus the effective switching frequency during this state is reduced to 1/4 of the normal switching frequency.

Signal clipping is signalled on the  $\overline{\text{CLIP}_\text{OTW}}$  pin and is self clearing when signal level reduces and the device reverts to normal operation. The  $\overline{\text{CLIP}_\text{OTW}}$  pulses start at the onset to output clipping, typically at a THD level around 0.01%, resulting in narrow CLIP\_OTW pulses starting with a pulse width of ~500 ns.

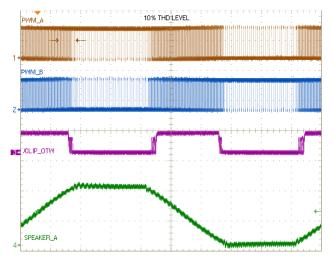


Figure 28. Signal Clipping PWM and Speaker Output Signals

#### 9.4.1.3 DC Speaker Protection

The output DC protection scheme protects a speaker from excess DC current in case one terminal of the speaker is connected to the amplifier while the other is accidentally shorted to the chassis ground. Such a short circuit results in a DC voltage of PVDD/2 across the speaker, which potentially can result in destructive current levels. The output DC protection detects any unbalance of the output and input current of a BTL output, and in the event of the unbalance exceeding a programmed threshold, the overload counter increments until its maximum value and the affected output channel is shut down. DC Speaker Protection is disabled in SE mode operation.



#### 9.4.1.4 Pin-to-Pin Short Circuit Protection (PPSC)

The PPSC detection system protects the device from permanent damage if a power output pin (OUT\_X) is shorted to GND\_X or PVDD\_X. For comparison, the OC protection system detects an overcurrent after the demodulation filter where PPSC detects shorts directly at the pin before the filter. PPSC detection is performed at startup that is, when VDD is supplied, consequently a short to either GND\_X or PVDD\_X after system startup does not activate the PPSC detection system. When PPSC detection is activated by a short on the output, all half bridges are kept in a Hi-Z state until the short is removed; the device then continues the startup sequence and starts switching. The detection is controlled globally by a two step sequence. The first step ensures that there are no shorts from OUT\_X to GND\_X, the second step tests that there are no shorts from OUT\_X to PVDD\_X. The total duration of this process is roughly proportional to the capacitance of the output LC filter. The typical duration is < 15ms/ $\mu$ F. While the PPSC detection is in progress, FAULT is kept low, and the device will not react to changes applied to the RESET pin. If no shorts are present the PPSC detection passes, and FAULT is released. A device reset will not start a new PPSC detection. PPSC detection is enabled in BTL and PBTL output configurations, the detection is not performed in SE mode. To make sure not to trip the PPSC detection system it is recommended not to insert a resistive load to GND\_X or PVDD\_X.

#### 9.4.1.5 Overtemperature Protection OTW and OTE

TPA3255 has a two-level temperature-protection system that asserts an active-low warning signal (CLIP\_OTW) when the device junction temperature exceeds 120°C (typical) and, if the device junction temperature exceeds 155°C (typical), the device is <u>put into</u> thermal shutdown, resulting in all half-bridge outputs being set in the highimpedance (Hi-Z) state and FAULT being asserted low. OTE is latched in this case. To clear the OTE latch, RESET must be asserted. Thereafter, the device resumes normal operation.

#### 9.4.1.6 Undervoltage Protection (UVP) and Power-on Reset (POR)

The UVP and POR circuits of the TPA3255 fully protect the device in any power-up/down and brownout situation. While powering up, the POR circuit ensures that all circuits are fully operational when the GVDD\_X and VDD supply voltages reach values stated in the *Electrical Characteristics* table. Although GVDD\_X and VDD are independently monitored, a supply voltage drop below the UVP threshold on any VDD or GVDD\_X pin results in all half-bridge outputs immediately being set in the high-impedance (Hi-Z) state and FAULT being asserted low. The device automatically resumes operation when all supply voltages have increased above the UVP threshold.

#### 9.4.1.7 Fault Handling

If a fault situation occurs while in operation, the device acts accordingly to the fault being a global or a channel fault. A global fault is a chip-wide fault situation and causes all PWM activity of the device to be shut down, and will assert FAULT low. A global fault is a latching fault and clearing FAULT and restarting operation requires resetting the device by toggling RESET. Deasserting RESET should never be allowed with excessive system temperature, so it is advised to monitor RESET by a system microcontroller and only allow releasing RESET (RESET high) if the CLIP\_OTW signal is cleared (high). A channel fault results in shutdown of the PWM activity of the affected channel(s). Note that asserting RESET low forces the FAULT signal high, independent of faults being present.

Fault/Event	Fault/Event Description	Global or Channel	Reporting Method	Latched/Self Clearing	Action needed to Clear	Output FETs
PVDD_X UVP						
VDD UVP	Voltage Fault	Global	FAULT pin	Self Clearing	Increase affected supply voltage	HI-Z
AVDD UVP					capp.j renage	
POR (DVDD UVP)	Power On Reset	Global	FAULT pin	Self Clearing	Allow DVDD to rise	HI-Z
BST_X UVP	Voltage Fault	Channel (Half Bridge)	None	Self Clearing	Allow BST cap to recharge (lowside ON, VDD 12V)	HighSide off
отw	Thermal Warning	Global	OTW pin	Self Clearing	Cool below OTW threshold	Normal operation
OTE	Thermal Shutdown	Global	FAULT pin	Latched	Toggle RESET	HI-Z
OLP (CB3C>1.7ms)	OC Shutdown	Channel	FAULT pin	Latched	Toggle RESET	HI-Z
Latched OC (47kΩ <roc_adj<68 kΩ)</roc_adj<68 	OC Shutdown	Channel	FAULT pin	Latched	Toggle RESET	HI-Z
CB3C (22kΩ <roc_adj<30 kΩ)</roc_adj<30 	OC Limiting	Channel	None	Self Clearing	Reduce signal level or remove short	Flip state, cycle by cycle at fs/3
Stuck at Fault <sup>(1)</sup>	No OSC_IO activity in Slave Mode	Global	None	Self Clearing	Resume OSC_IO activity	HI-Z

#### Table 5. Error Reporting

(1) Stuck at Fault occurs when input OSC\_IO input signal frequency drops below minimum frequency given in the *Electrical Characteristics* table of this data sheet.

#### 9.4.1.8 Device Reset

Asserting RESET low initiates the device ramp down. The output FETs go into a Hi-Z state after the ramp down is complete. Output pull downs are active both in SE mode and BTL mode with RESET low.

In BTL modes, to accommodate bootstrap charging prior to switching start, asserting the reset input low enables weak pulldown of the half-bridge outputs.

Asserting reset input low removes any fault information to be signaled on the FAULT output, that is, FAULT is forced high. A rising-edge transition on reset input allows the device to resume operation after a fault. To ensure thermal reliability, the rising edge of reset must occur no sooner than 4 ms after the falling edge of FAULT.



### **10** Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### **10.1** Application Information

TPA3255 can be configured either in stereo BTL mode, 4 channel SE mode, mono PBTL mode, or in 2.1 mixed 1x BTL + 2x SE mode depending on output power conditions and system design.

#### **10.2 Typical Applications**

#### 10.2.1 Stereo BTL Application

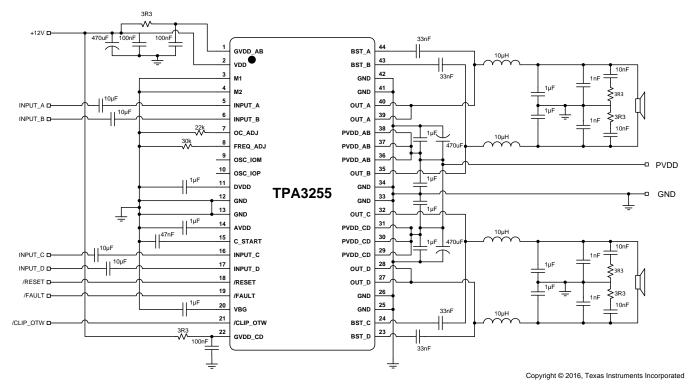


Figure 29. Typical Differential (2N) BTL Application



#### **Typical Applications (continued)**

#### 10.2.1.1 Design Requirements

For this design example, use the parameters in Table 6.

Table 6. Design Requirements, BTL Application			
DESIGN PARAMETER	EXAMPLE		
Low Power (Pull-up) Supply	3.3 V		
Mid Power Supply 12 V	12 V		
High Power Supply	18 - 51 V		
Mode Selection	M2 = L		
	M1 = L		
	INPUT_A = ±3.9 V (peak, max)		
Analog Innuto	$INPUT_B = \pm 3.9V$ (peak, max)		
Analog Inputs	INPUT_C = ±3.9 V (peak, max)		
	INPUT_D = ±3.9 V (peak, max)		
Output Filters	Inductor-Capacitor Low Pass FIlter (10 μH + 1 μF)		
Speaker Impedance	3-8 Ω		

#### 10.2.1.2 Detailed Design Procedures

A rising-edge transition on reset input allows the device to execute the startup sequence and starts switching.

The CLIP signal is indicating that the output is approaching clipping. The signal can be used either to decrease audio volume or to control an intelligent power supply nominally operating at a low rail adjusting to a higher supply rail.

The device is inverting the audio signal from input to output.

The DVDD and AVDD pins are not recommended to be used as a voltage sources for external circuitry.

#### 10.2.1.2.1 Decoupling Capacitor Recommendations

In order to design an amplifier that has robust performance, passes regulatory requirements, and exhibits good audio performance, good quality decoupling capacitors should be used. In practice, X7R should be used in this application.

#### 10.2.1.2.2 PVDD Capacitor Recommendation

The PVDD decoupling capacitors must be placed as close to the device pins a possible to insure short trace length and low a low inductance path. Likewise the ground path for these capacitors must provide a good reference and should be substantial. This will keep voltage ringing on PVDD to a minimum.

The voltage of the decoupling capacitors should be selected in accordance with good design practices. Temperature, ripple current, and voltage overshoot must be considered. This fact is particularly true in the selection of the  $1\mu$ F that is placed on the power supply to each full-bridge. It must withstand the voltage overshoot of the PWM switching, the heat generated by the amplifier during high power output, and the ripple current created by high power output. A minimum voltage rating of 100 V is required for use with a 51-V power supply.

The large capacitors used in conjunction with each full-bridge, are referred to as the PVDD Capacitors. These capacitors should be selected for proper voltage margin and adequate capacitance to support the power requirements. In practice, with a well designed system power supply, 1000  $\mu$ F, 80 V supports most applications. The PVDD capacitors should be low ESR type because they are used in a circuit associated with high-speed switching.

#### 10.2.1.2.3 PCB Material Recommendation

FR-4 Glass Epoxy material with 2 oz. (70  $\mu$ m) copper is recommended for use with the TPA3255. The use of this material can provide for higher power output, improved thermal performance, and better EMI margin (due to lower PCB trace inductance.

Copyright © 2016, Texas Instruments Incorporated



#### 10.2.1.2.4 Oscillator

The built in oscillator frequency can be trimmed by an external resistor from the FREQ\_ADJ pin to GND. Changes in the oscillator frequency should be made with resistor values specified in *Recommended Operating Conditions* while RESET is low.

To reduce interference problems while using a radio receiver tuned within the AM band, the switching frequency can be changed from nominal to lower or higher values. These values should be chosen such that the nominal and the alternate switching frequencies together result in the fewest cases of interference throughout the AM band. The oscillator frequency can be selected by the value of the FREQ\_ADJ resistor connected to GND in master mode.

For slave mode operation, turn off the oscillator by pulling the FREQ\_ADJ pin to DVDD. This configures the OSC\_I/O pins as inputs to be slaved from an external differential clock. In a master/slave system inter-channel delay is automatically set up between the switching of the audio channels, which can be illustrated by no idle channels switching at the same time. This will not influence the audio output, but only the switch timing to minimize noise coupling between audio channels through the power supply. Inter-channel delay is needed to optimize audio performance and to get better operating conditions for the power supply. The inter-channel delay will be set up for a slave device depending on the polarity of the OSC\_I/O connection as follows:

- Slave 1 mode has normal polarity (master + to slave + and master to slave -)
- Slave 2 mode has reverse polarity (master + to slave and master to slave +)

The interchannel delay for interleaved channel idle switching is given in the table below for the master/slave and output configuration modes in degrees relative to the PWM frame.

	*			
Master	M1 = 0, M2 = 0, 2 x BTL mode	M1 = 1, M2 = 0, 1 x BTL + 2 x SE mode	M1 = 0, M2 = 1, 1 x PBTL mode	M1 = 1, M2 = 1, 4 x SE mode
OUT_A	0°	0°	0°	0°
OUT_B	180°	180°	180°	60°
OUT_C	60°	60°	0°	0°
OUT_D	240°	120°	180°	60°
Slave 1				
OUT_A	60°	60°	60°	60°
OUT_B	240°	240°	240°	120°
OUT_C	120°	120°	60°	60°
OUT_D	300°	180°	240°	120°
Slave 2				
OUT_A	30°	30°	30°	30°
OUT_B	210°	210°	210°	90°
OUT_C	90°	90°	30°	30°
OUT_D	270°	150°	210°	90°

Table 7. Master/Slave Inter Channel Delay Settings



### 10.2.2 Application Curves

Relevant performance plots for TPA3255 in BTL configuration are shown in *Typical Characteristics, BTL Configuration* 

	-
PLOT TITLE	FIGURE NUMBER
Total Harmonic Distortion+Noise vs Frequency	Figure 1
Total Harmonic Distortion+Noise vs Frequency, 80kHz analyzer BW	Figure 2
Total Harmonic Distortion + Noise vs Output Power	Figure 5
Output Power vs Supply Voltage, 10% THD+N	Figure 7
Output Power vs Supply Voltage, 10% THD+N	Figure 9
System Efficiency vs Output Power	Figure 9
System Power Loss vs Output Power	Figure 10
Output Power vs Case Temperature	Figure 11
Noise Amplitude vs Frequency	Figure 12

#### Table 8. Relevant Performance Plots, BTL Configuration

Copyright © 2016, Texas Instruments Incorporated

TPA3255	
JAJSD69A-FEI	BRUARY 2016-REVISED OCTOBER 2016

### 10.2.3 Typical Application, Single Ended (1N) SE

TPA3255 can be configured either in stereo BTL mode, 4 channel SE mode, mono PBTL mode, or in 2.1 mixed 1x BTL + 2x SE mode depending on output power conditions and system design.

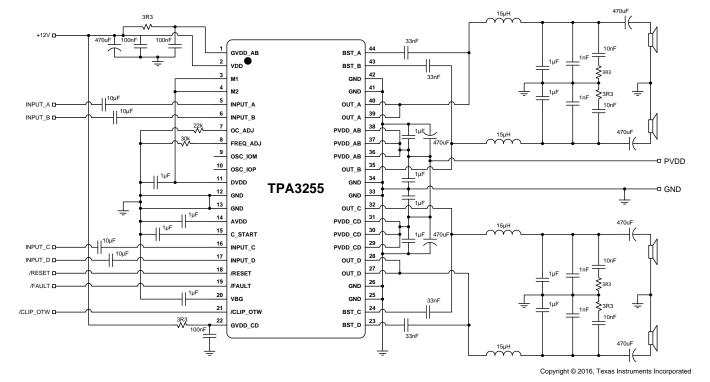


Figure 30. Typical Single Ended (1N) SE Application

#### 10.2.3.1 Design Requirements

Refer to Stereo BTL Application for the Design Requirements.

	equilemente, e= , ppression				
DESIGN PARAMETER	EXAMPLE				
Low Power (Pull-up) Supply	3.3 V				
Mid Power Supply 12 V	12 V				
High Power Supply	18 - 51 V				
Marka Oslastian	M2 = H				
Mode Selection	M1 = H				
	INPUT_A = ±3.9 V (peak, max)				
Angles legiste	INPUT_B = ±3.9 V (peak, max)				
Analog Inputs	INPUT_C = ±3.9 V (peak, max)				
	INPUT_D = ±3.9 V (peak, max)				
Output Filters	Inductor-Capacitor Low Pass Fllter (15 µH + 680 nF)				
Speaker Impedance	2 - 8 Ω				

#### Table 9. Design Requirements, SE Application

#### 10.2.3.2 Detailed Design Procedures

Refer to Stereo BTL Application for the Detailed Design Procedures.





### 10.2.3.3 Application Curves

Relevant performance plots for TPA3255 in PBTL configuration are shown in *Typical Characteristics, SE Configuration* 

PLOT TITLE	FIGURE NUMBER
Total Harmonic Distortion+Noise vs Output Power	Figure 13
Total Harmonic Distortion+Noise vs Frequency	Figure 14
Total Harmonic Distortion+Noise vs Frequency, 80kHz analyzer BW	Figure 15
Output Power vs Supply Voltage, 10% THD+N	Figure 16
Output Power vs Supply Voltage, 1% THD+N	Figure 17
Output Power vs Case Temperature	Figure 18

#### Table 10. Relevant Performance Plots, SE Configuration



**NSTRUMENTS** 

**Texas** 

### 10.2.4 Typical Application, Differential (2N) PBTL

TPA3255 can be configured either in stereo BTL mode, 4 channel SE mode, mono PBTL mode, or in 2.1 mixed 1x BTL + 2x SE mode depending on output power conditions and system design.

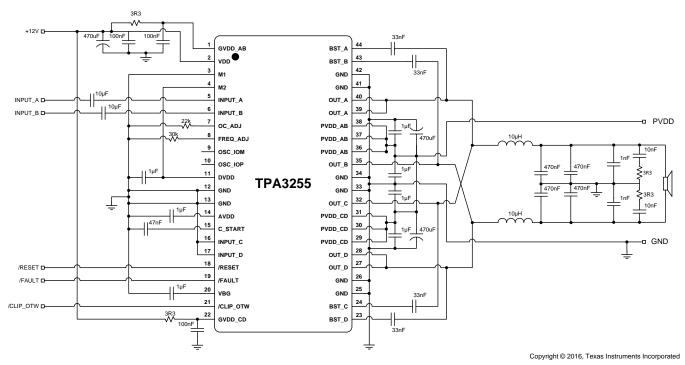


Figure 31. Typical Differential (2N) PBTL Application

### 10.2.4.1 Design Requirements

Refer to Stereo BTL Application for the Design Requirements.

5	
DESIGN PARAMETER	EXAMPLE
Low Power (Pull-up) Supply	3.3 V
Mid Power Supply 12 V	12 V
High Power Supply	18 - 51 V
Marta Ostastisa	M2 = H
Mode Selection	M1 = L
	INPUT_A = ±3.9V (peak, max)
Anglen Lengte	$INPUT_B = \pm 3.9V$ (peak, max)
Analog Inputs	INPUT_C = Grounded
	INPUT_D = Grounded
Output Filters	Inductor-Capacitor Low Pass FIlter (10 µH + 1 µF)
Speaker Impedance	2 - 4 Ω

Table 11.	Desian	Reaui	rements.	PBTL	Ap	olication
	_ 00.g.				· • • • •	on out on

#### 10.2.4.2 Detailed Design Procedures

Refer to Stereo BTL Application for the Detailed Design Procedures.



#### 10.2.4.3 Application Curves

Relevant performance plots for TPA3255 in PBTL configuration are shown in *Typical Characteristics, PBTL Configuration* 

PLOT TITLE	FIGURE NUMBER
Total Harmonic Distortion+Noise vs Output Power	Figure 19
Total Harmonic Distortion+Noise vs Frequency	Figure 20
Total Harmonic Distortion+Noise vs Frequency, 80kHz analyzer BW	Figure 21
Output Power vs Supply Voltage, 10% THD+N	Figure 22
Output Power vs Supply Voltage, 1% THD+N	Figure 23
Output Power vs Case Temperature	Figure 24

### 11 Power Supply Recommendations

#### **11.1 Power Supplies**

The TPA3255 device requires two external power supplies for proper operation. A high-voltage supply called PVDD is required to power the output stage of the speaker amplifier and its associated circuitry. Additionally, one mid-voltage power supply for GVDD\_X and VDD is required to power the gate-drive and other internal digital and analog portions of the device. The allowable voltage range for both the PVDD and the GVDD\_X/VDD supplies are listed in the *Recommended Operating Conditions* table. Ensure both the PVDD and the GVDD\_X/VDD supplies can deliver more current than listed in the *Electrical Characteristics* table.

#### 11.1.1 VDD Supply

The VDD supply required from the system is used to power several portions of the device. It provides power to internal regulators DVDD and AVDD that are used to power digital and analog sections of the device, respectively. Proper connection, routing, and decoupling techniques are highlighted in the TPA3255 device EVM User's Guide SLOU441 (as well as the *Application Information* section and *Layout Examples* section) and must be followed as closely as possible for proper operation and performance. Deviation from the guidance offered in the TPA3255 device EVM User's Guide, which followed the same techniques as those shown in the *Application Information* section, may result in reduced performance, errant functionality, or even damage to the TPA3255 device. Some portions of the device also require a separate power supply which is a lower voltage than the VDD supply. To simplify the power supply requirements for the system, the TPA3255 device includes integrated low-dropout (LDO) linear regulators to create these supplies. These linear regulators are internally connected to the VDD supply and their outputs are presented on AVDD and DVDD pins, providing a connection point for an external bypass capacitors. It is important to note that the linear regulators integrated in the device have only been designed to support the current requirements of the internal circuitry, and should not be used to power any additional external circuitry. Additional loading on these pins could cause the voltage to sag and increase noise injection, which negatively affects the performance and operation of the device.

#### 11.1.2 GVDD\_X Supply

The GVDD\_X supply required from the system is used to power the gate-drives for the output H-bridges. Proper connection, routing, and decoupling techniques are highlighted in the TPA3255 device EVM User's Guide SLOU441 (as well as the *Application Information* section and *Layout Examples* section) and must be followed as closely as possible for proper operation and performance. Deviation from the guidance offered in the TPA3255 device EVM User's Guide, which followed the same techniques as those shown in the *Application Information* section, may result in reduced performance, errant functionality, or even damage to the TPA3255 device.



#### **Power Supplies (continued)**

#### 11.1.3 PVDD Supply

The output stage of the amplifier drives the load using the PVDD supply. This is the power supply which provides the drive current to the load during playback. Proper connection, routing, and decoupling techniques are highlighted in the TPA3255 device EVM User's Guide SLOU441 (as well as the *Application Information* section and *Layout Examples* section) and must be followed as closely as possible for proper operation and performance. Due the high-voltage switching of the output stage, it is particularly important to properly decouple the output power stages in the manner described in the TPA3255 device EVM User's Guide, can results in voltage spikes which can damage the device, or cause poor audio performance and device shutdown faults.

#### 11.2 Powering Up

The TPA3255 does not require a power-up sequence, but it is recommended to hold RESET low for at least 250 ms after PVDD supply voltage is turned ON. The outputs of the H-bridges remain in a high-impedance state until the gate-drive supply voltage (GVDD\_X) and VDD voltages are above the undervoltage protection (UVP) voltage threshold (see the *Electrical Characteristics* table of this data sheet). This allows an internal circuit to charge the external bootstrap capacitors by enabling a weak pulldown of the half-bridge output as well as initiating a controlled ramp up sequence of the output voltage.

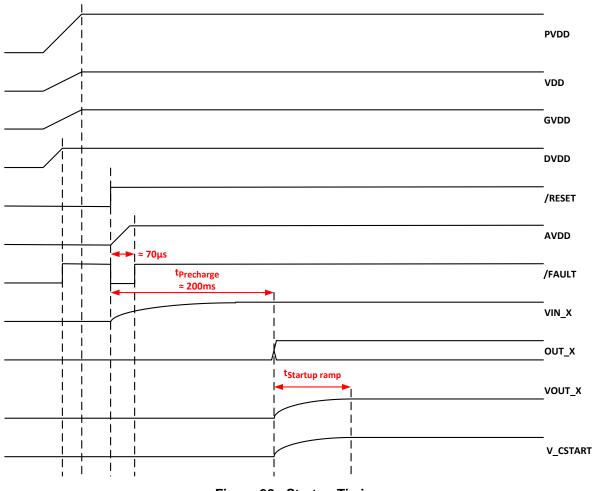


Figure 32. Startup Timing

When RESET is released to turn on TPA3255, FAULT signal will turn low and AVDD voltage regulator will be enabled. FAULT will stay low until AVDD reaches the undervoltage protection (UVP) voltage threshold (see the Electrical Characteristics table of this data sheet). After a precharge time to stabilize the DC voltage across the input AC coupling capacitors, the ramp up sequence starts.



#### 11.3 Powering Down

The TPA3255 does not require a power-down sequence. The device remains fully operational as long as the gate-drive supply (GVDD\_X) voltage and VDD voltage are above the undervoltage protection (UVP) voltage threshold (see the *Electrical Characteristics* table of this data sheet). Although not specifically required, it is a good practice to hold RESET low during power down, thus preventing audible artifacts including pops or clicks by initiating a controlled ramp down sequence of the output voltage.

#### 11.4 Thermal Design

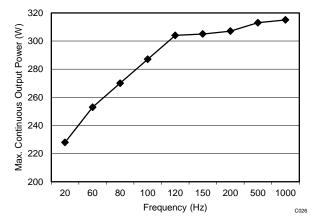
#### 11.4.1 Thermal Performance

TPA3255 thermal performance is dependent on the design of the thermal system, which is the heatsink design and surrounding conditions including system enclosure (closed box with no air flow, or a fanned system etc.). As a result, the maximum continuous output power attainable will be influenced by the thermal design.

To mitigate thermal limitations in systems with the device operated at continuous high power it is advised to increase the cooling capability of the thermal system, or to operate the device in PBTL operation mode.

#### **11.4.2** Thermal Performance with Continuous Output Power

It is recommended to operate TPA3255 below the OTW threshold. In most systems normal use conditions will safely keep the device temperature with margin to the OTW threshold. However in some systems and use cases the device temperature can run high, dependent on the actual output power, operating voltage, and thermal system. At high operating temperature some thermal limitations for continuous output power may occur at low audio frequencies due to increased heating of the output MOSFETs. Figure 33 shows maximum attainable continuous output power with a heatsink temperature of 75°C and maximum 10% THD.





#### 11.4.3 Thermal Performance with Non-Continuous Output Power

As audio signals often have a peak to average ratio larger than one (average level below maximum peak output), the thermal performance for audio signals can be illustrated using burst signals with different burst ratios.

TEXAS INSTRUMENTS

www.ti.com

### Thermal Design (continued)

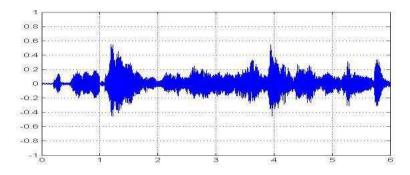


Figure 34. Example of audio signal

A burst signal is characterized by the high-level to low-level ratio as well as the duration of the high level and low level, e.g. a burst 1:4 stimuli is a single period of high level followed by 4 cycles of low level.

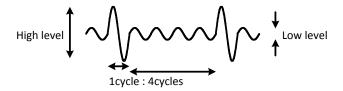
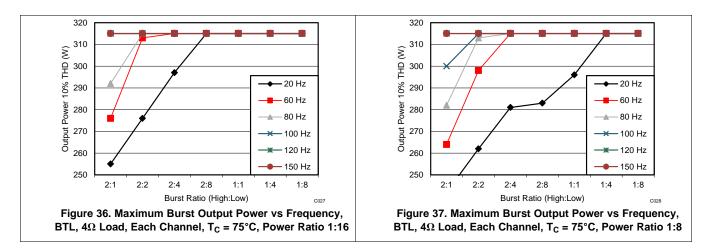


Figure 35. Example of 1:4 Burst Signal

The following analysis of thermal performance for TPA3255 is made with the heatsink temperature controlled to 75°C.

The device is not thermally limited with  $8-\Omega$  load, but depending on the burst stimuli for operation at 75°C heatsink temperature some thermal limitations may occur with a lower load impedance, depending on switching frequency and average to maximum power ratio. The figure below shows burst performance with a signal power ratio of 1:16 (low cycles power level 1/16 of the high cycles power level) and 1:8.





## 12 Layout

#### 12.1 Layout Guidelines

- Use an unbroken ground plane to have good low impedance and inductance return path to the power supply for power and audio signals.
- Maintain a contiguous ground plane from the ground pins to the PCB area surrounding the device for as many of the ground pins as possible, since the ground pins are the best conductors of heat in the package.
- PCB layout, audio performance and EMI are linked closely together.
- Routing the audio input should be kept short and together with the accompanied audio source ground.
- The small bypass capacitors on the PVDD lines of the DUT be placed as close the PVDD pins as possible.
- A local ground area underneath the device is important to keep solid to minimize ground bounce.
- Orient the passive component so that the narrow end of the passive component is facing the TPA3255 device, unless the area between two pads of a passive component is large enough to allow copper to flow in between the two pads.
- Avoid placing other heat producing components or structures near the TPA3255 device.
- Avoid cutting off the flow of heat from the TPA3255 device to the surrounding ground areas with traces or via strings, especially on output side of device.

Netlist for this printed circuit board is generated from the schematic in Figure 38.

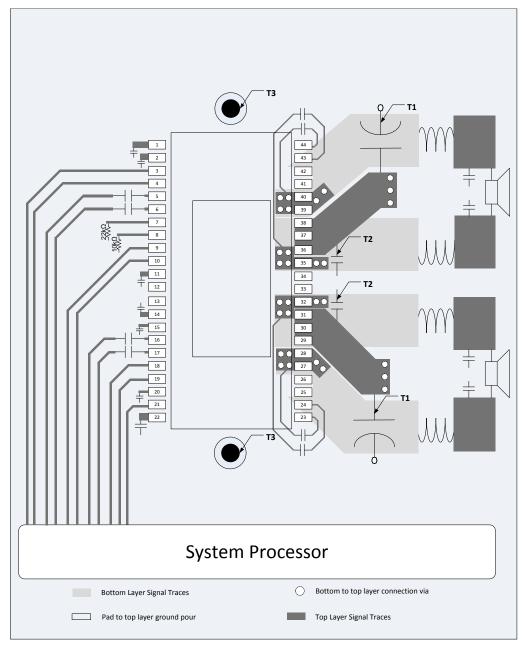
**TPA3255** JAJSD69A – FEBRUARY 2016 – REVISED OCTOBER 2016



www.ti.com

#### 12.2 Layout Examples

#### 12.2.1 BTL Application Printed Circuit Board Layout Example



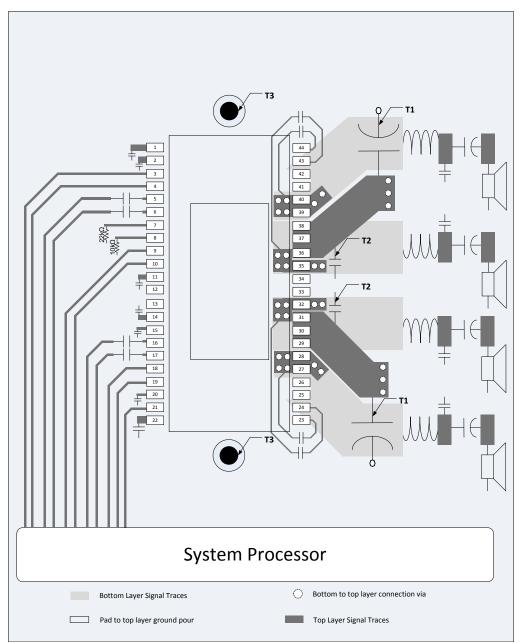
- A. Note: PCB layout example shows composite layout. Dark grey: Top layer copper traces, light gray: Bottom layer copper traces. All PCB area not used for traces should be GND copper pour (transparent on example image)
- B. **Note T1**: PVDD decoupling bulk capacitors should be as close as possible to the PVDD and GND\_X pins, the heat sink sets the distance. Wide traces should be routed on the top layer with direct connection to the pins and without going through vias. No vias or traces should be blocking the current path.
- C. Note T2: Close decoupling of PVDD with low impedance X7R ceramic capacitors is placed under the heat sink and close to the pins.
- D. Note T3: Heat sink needs to have a good connection to PCB ground.

#### Figure 38. BTL Application Printed Circuit Board - Composite



#### Layout Examples (continued)

#### 12.2.2 SE Application Printed Circuit Board Layout Example



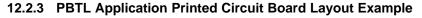
- A. Note: PCB layout example shows composite layout. Dark grey: Top layer copper traces, light gray: Bottom layer copper traces. All PCB area not used for traces should be GND copper pour (transparent on example image)
- B. **Note T1**: PVDD decoupling bulk capacitors should be as close as possible to the PVDD and GND\_X pins, the heat sink sets the distance. Wide traces should be routed on the top layer with direct connection to the pins and without going through vias. No vias or traces should be blocking the current path.
- C. Note T2: Close decoupling of PVDD with low impedance X7R ceramic capacitors is placed under the heat sink and close to the pins.
- D. Note T3: Heat sink needs to have a good connection to PCB ground.

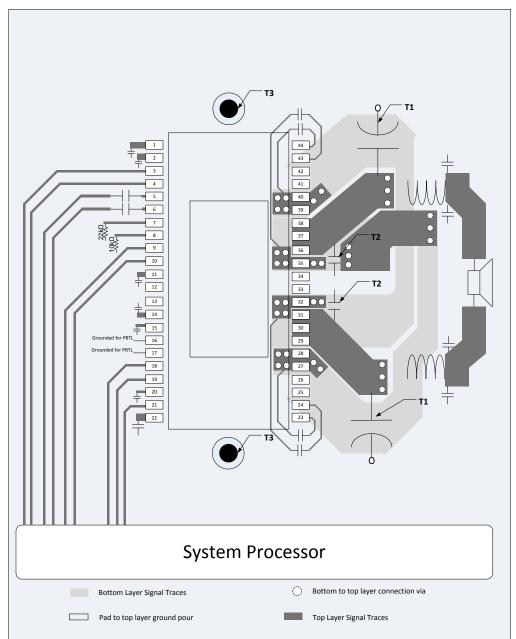
#### Figure 39. SE Application Printed Circuit Board - Composite



www.tij.co.jp

#### Layout Examples (continued)





- A. Note: PCB layout example shows composite layout. Dark grey: Top layer copper traces, light gray: Bottom layer copper traces. All PCB area not used for traces should be GND copper pour (transparent on example image)
- B. **Note T1**: PVDD decoupling bulk capacitors should be as close as possible to the PVDD and GND\_X pins, the heat sink sets the distance. Wide traces should be routed on the top layer with direct connection to the pins and without going through vias. No vias or traces should be blocking the current path.
- C. Note T2: Close decoupling of PVDD with low impedance X7R ceramic capacitors is placed under the heat sink and close to the pins.
- D. ote T3: Heat sink needs to have a good connection to PCB ground.

#### Figure 40. PBTL Application Printed Circuit Board - Composite



#### www.tij.co.jp

## 13 デバイスおよびドキュメントのサポート

### 13.1 ドキュメントのサポート

『TPA3255D2EVMユーザー・ガイド』、SLOU441

### 13.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「通 知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の 詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 13.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™オンライン・コミュニティ *TIのE2E(Engineer-to-Engineer)コミュニティ。*エンジニア間の共同作 業を促進するために開設されたものです。e2e.ti.comでは、他のエンジニアに質問し、知識を共有 し、アイディアを検討して、問題解決に役立てることができます。

設計サポート TIの設計サポート 役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることが できます。技術サポート用の連絡先情報も参照できます。

#### 13.4 商標

PurePath, E2E are trademarks of Texas Instruments. Blu-Ray Disc is a trademark of Blu-ray Disc Association. All other trademarks are the property of their respective owners.

#### 13.5 静電気放電に関する注意事項



これらのデバイスは、限定的なESD(静電破壊)保護機能を内 蔵しています。保存時または取り扱い時は、MOSゲートに対す る静電破壊を防 ▲ 上するために、リード線同士をショートさせておくか、デバイスを導電フォームに入れる必要があります。

#### 13.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 14 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスに ついて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もありま す。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。



10-Dec-2020

### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPA3255DDV	ACTIVE	HTSSOP	DDV	44	35	RoHS & Green	NIPDAU	Level-3-260C-168 HR	0 to 70	3255	Samples
TPA3255DDVR	ACTIVE	HTSSOP	DDV	44	2000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	0 to 70	3255	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



## PACKAGE OPTION ADDENDUM

10-Dec-2020

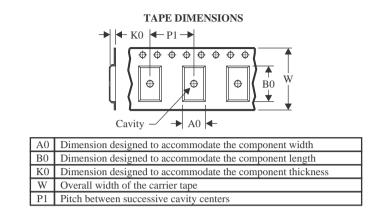


Texas

NSTRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions	are nominal
-----------------	-------------

Device	0	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	` '	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA3255DDVR	HTSSOP	DDV	44	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1



# PACKAGE MATERIALS INFORMATION

5-Dec-2023



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA3255DDVR	HTSSOP	DDV	44	2000	350.0	350.0	43.0

### TEXAS INSTRUMENTS

www.ti.com

5-Dec-2023

### TUBE



## - B - Alignment groove width

\*All dimensions are nominal

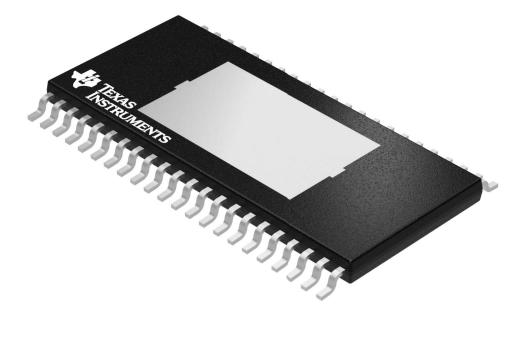
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
TPA3255DDV	DDV	HTSSOP	44	35	530	11.89	3600	4.9

## **GENERIC PACKAGE VIEW**

# DDV 44

# PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

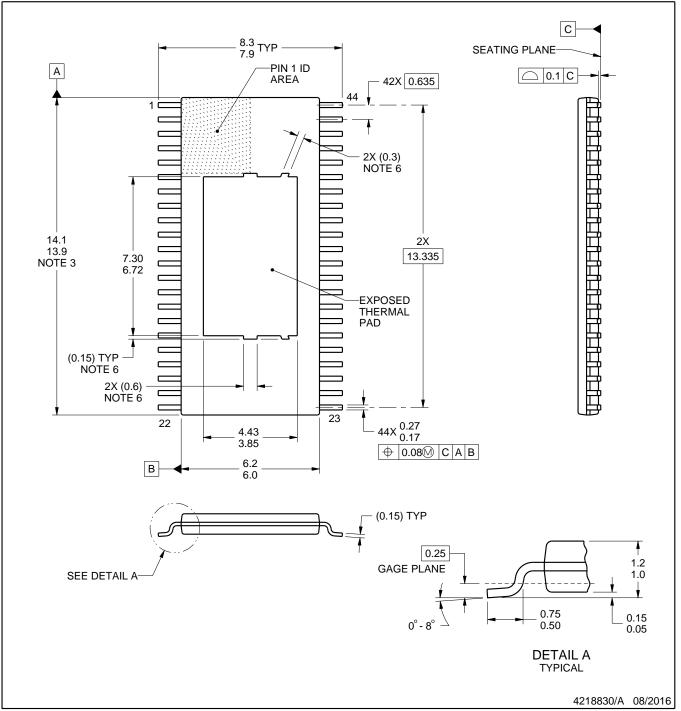


## **PACKAGE OUTLINE**

# **DDV0044D**

## PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



#### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  This drawing is subject to change without notice.
  This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.
- 5. The exposed thermal pad is designed to be attached to an external heatsink.
- 6. Features may differ or may not be present.

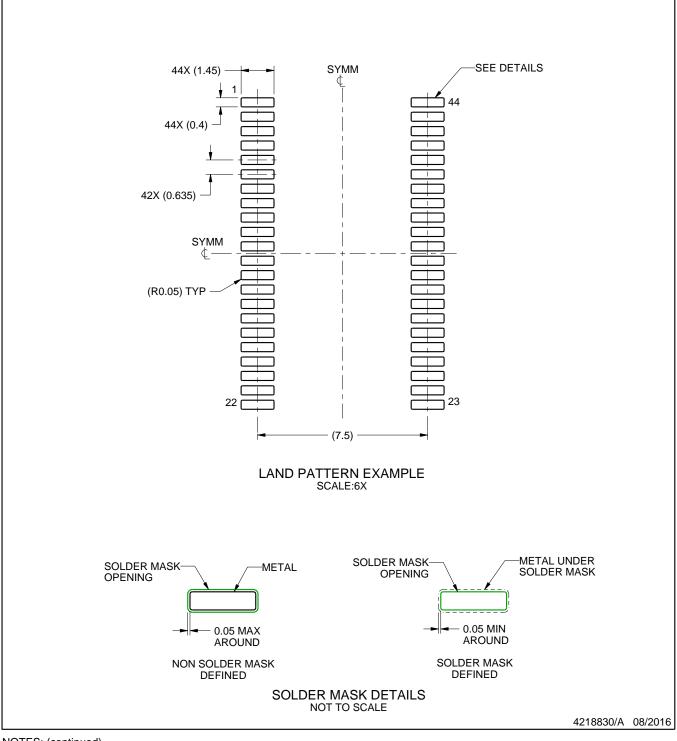


# **DDV0044D**

# **EXAMPLE BOARD LAYOUT**

## PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.

8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

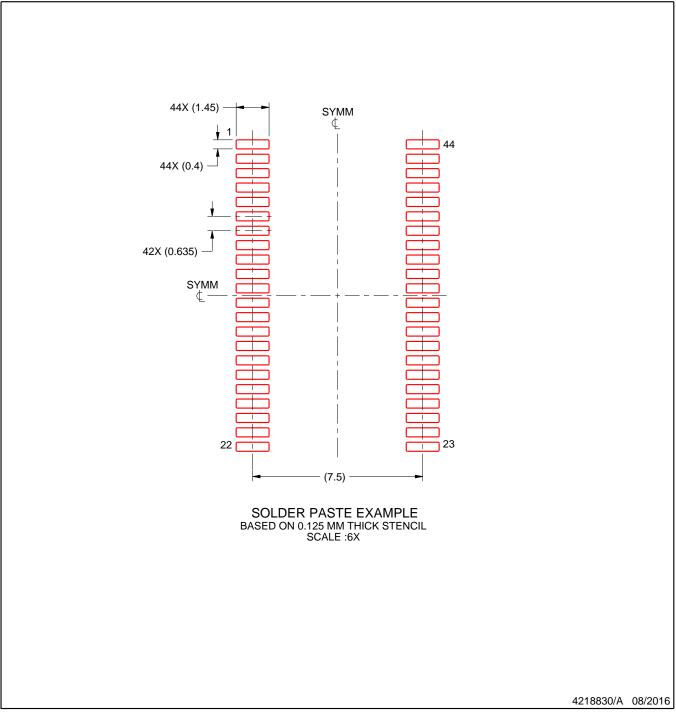


# **DDV0044D**

# **EXAMPLE STENCIL DESIGN**

# PowerPAD<sup>™</sup> TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

10. Board assembly site may have different recommendations for stencil design.



#### 重要なお知らせと免責事項

TIは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス・デザインを含みます)、アプリケーションや 設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供してお り、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的に かかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあら ゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプ リケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載す ることは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを 自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TIの製品は、TIの販売条件、または ti.com やかかる TI 製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供され ています。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありま せん。

お客様がいかなる追加条項または代替条項を提案した場合でも、TIはそれらに異議を唱え、拒否します。

郵送先住所:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated